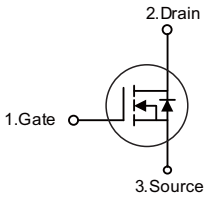
| | | |
|---|---|---|
| $V_{DSS}$ | 60 | V |
| $I_D$ | 50 | A |
| $R_{DS(ON)}$ | 11m | Ω |

## FEATURES

100% EAS Guaranteed
Green Device Available
Super Low Gate Charge
Excellent CdV/dt effect decline
Advanced high cell density Trench technology




## APPLICATION

The 50N06 is the high cell density trenched N-ch MOSFETs, which provide excellent RDSON and gate charge for most of the synchronous buck converter applications.

The 50N06 meet the RoHS and Green Product requirement, 100% EAS guaranteed with full function reliability approved.

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

### Absolute Maximum Ratings ($T_C$=25℃ unless otherwise specified)

| Symbol | Parameter | | Max. | Units |
|---|---|---|---|---|
| $V_{DSS}$ | Drain-Source Voltage | | 60 | V |
| $V_{GSS}$ | Gate-Source Voltage | | ±20 | V |
| $I_D$ | Continuous Drain Current | $T_C$ = 25℃ | 50 | A |
| | | $T_C$ = 100℃ | 29 | A |
| $I_{DM}$ | Pulsed Drain Current note1 | | 180 | A |
| $E_{AS}$ | Single Pulsed Avalanche Energy note2 | | 36 | mJ |
| $P_D$ | Power Dissipation | $T_C$ = 25℃ | 60 | W |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case | | 2.5 | ℃/W |
| $T_J$, $T_{STG}$ | Operating and Storage Temperature Range | | -55 to +150 | ℃ |

## Electrical characteristics ($T_J$=25℃ unless otherwise noted)

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Units |
|---|---|---|---|---|---|---|
| **Off Characteristic** | | | | | | |
| $V_{(BR)DSS}$ | Drain-Source Breakdown Voltage | $V_{GS}$=0V, $I_D$=250μA | 60 | - | - | V |
| $I_{DSS}$ | Zero Gate Voltage Drain Current | $V_{DS}$=60V, $V_{GS}$=0V, | - | - | 1.0 | μA |
| $I_{GSS}$ | Gate to Body Leakage Current | $V_{DS}$=0V, $V_{GS}$= ±20V | - | - | ±100 | nA |
| **On Characteristics** | | | | | | |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{DS}$=$V_{GS}$, $I_D$=250μA | 1.0 | 1.6 | 2.5 | V |
| $R_{DS(on)}$ | Static Drain-Source on-Resistance note3 | $V_{GS}$=10V, $I_D$=20A | - | 11 | 17 | mΩ |
| | | $V_{GS}$=4.5V, $I_D$=10A | - | 14 | 25 | |
| **Dynamic Characteristics** | | | | | | |
| $C_{iss}$ | Input Capacitance | $V_{DS}$=25V, $V_{GS}$=0V, f=1.0MHz | - | 930 | - | pF |
| $C_{oss}$ | Output Capacitance | | - | 230 | - | pF |
| $C_{rss}$ | Reverse Transfer Capacitance | | - | 8 | - | pF |
| $Q_g$ | Total Gate Charge | $V_{DS}$=30V, $I_D$=20A, $V_{GS}$=10V | - | 22 | - | nC |
| $Q_{gs}$ | Gate-Source Charge | | - | 4.5 | - | nC |
| $Q_{gd}$ | Gate-Drain(“Miller”) Charge | | - | 3.5 | - | nC |
| **Switching Characteristics** | | | | | | |
| $t_{d(on)}$ | Turn-on Delay Time | $V_{DD}$=30V, $I_D$=20A, $R_G$=1.6Ω, $V_{GS}$=10V | - | 4.5 | - | ns |
| $t_r$ | Turn-on Rise Time | | - | 2.7 | - | ns |
| $t_{d(off)}$ | Turn-off Delay Time | | - | 13.8 | - | ns |
| $t_f$ | Turn-off Fall Time | | - | 2.7 | - | ns |
| **Drain-Source Diode Characteristics and Maximum Ratings** | | | | | | |
| $I_S$ | Maximum Continuous Drain to Source Diode Forward Current | | - | - | 45 | A |
| $I_{SM}$ | Maximum Pulsed Drain to Source Diode Forward Current | | - | - | 180 | A |
| $V_{SD}$ | Drain to Source Diode Forward Voltage | $V_{GS}$=0V, $I_S$=30A | - | - | 1.2 | V |
| $t_{rr}$ | Body Diode Reverse Recovery Time | $T_J$=25℃, $I_F$=20A,dI/dt=100A/μs | - | 18 | - | ns |
| $Q_{rr}$ | Body Diode Reverse Recovery Charge | | - | 12 | - | nC |

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

2. EAS condition: $T_J$=25℃, $V_{DD}$=30V, $V_G$=10V, $R_G$=25Ω, L=0.5mH, $I_{AS}$=12A

3. Pulse Test: Pulse Width≤300μs, Duty Cycle≤0.5%

## RATING AND CHARACTERISTIC CURVES

**Figure1:** Output Characteristics

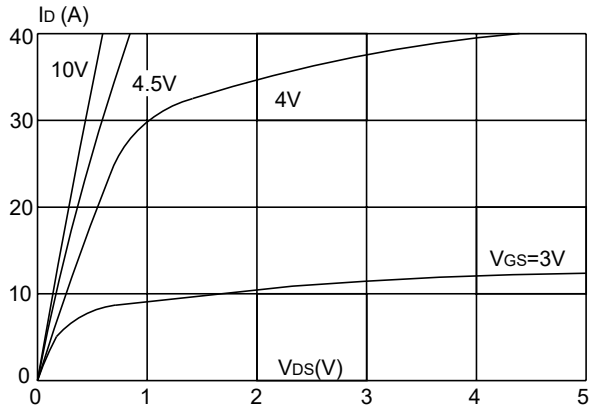



**Figure 2:** Typical Transfer Characteristics

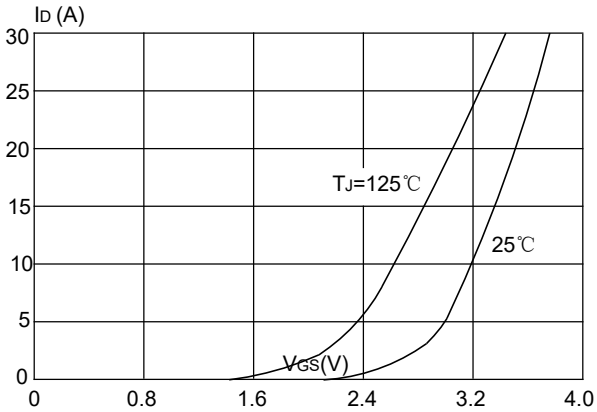



**Figure 3:**On-resistance vs. Drain Current

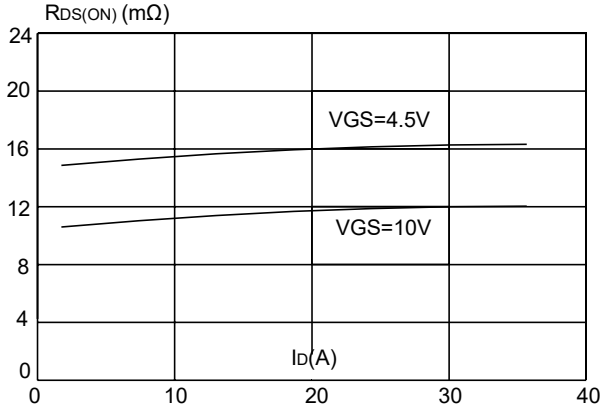



**Figure 4**: Body Diode Characteristics

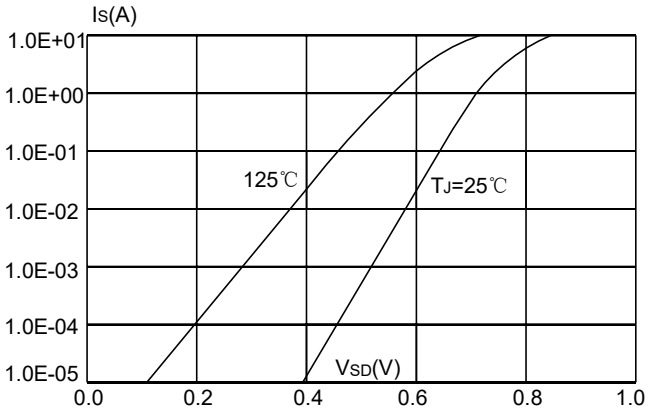



**Figure 5:** Gate Charge Characteristics

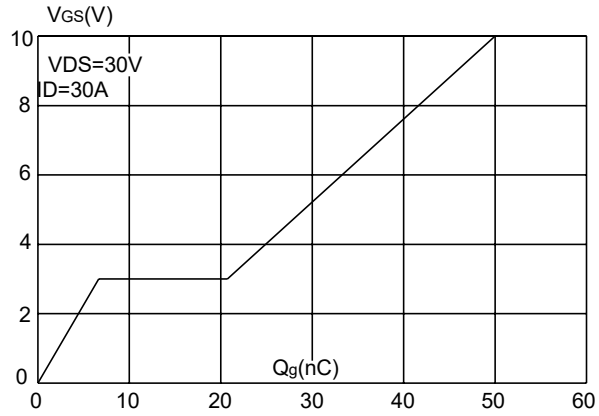
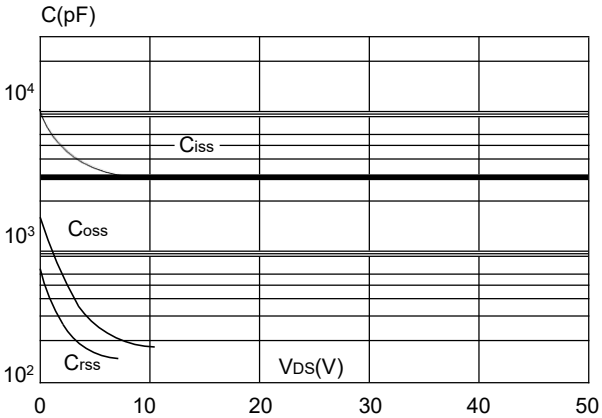



**Figure 6:** Capacitance Characteristics



## RATING AND CHARACTERISTIC CURVES

**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature

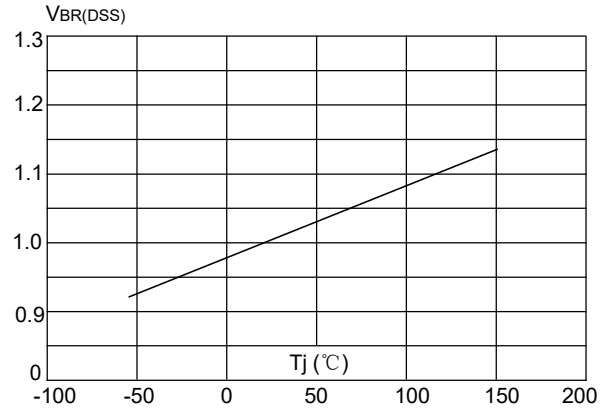



**Figure 8:** Normalized on Resistance vs. Junction Temperature

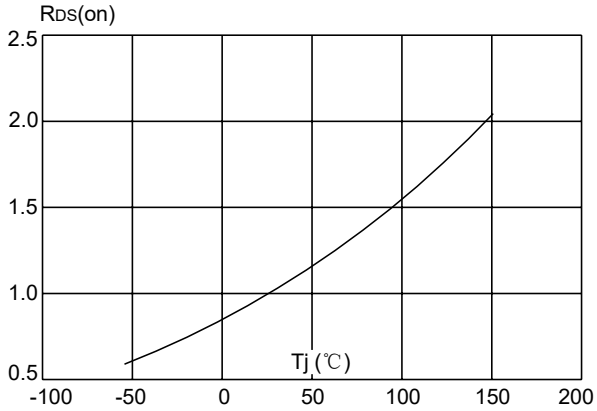



**Figure 9:** Maximum Safe Operating Area

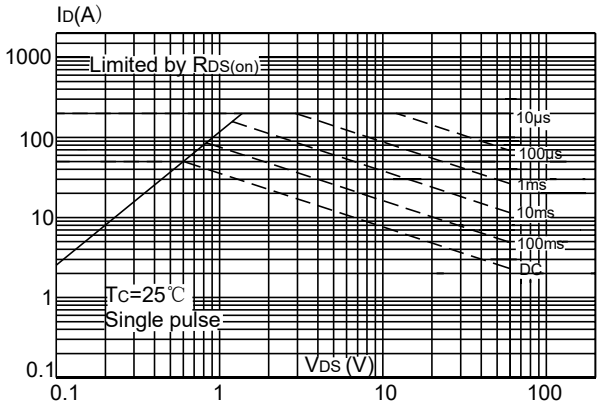



**Figure 10:** Maximum Continuous Drain Current vs. Case Temperature

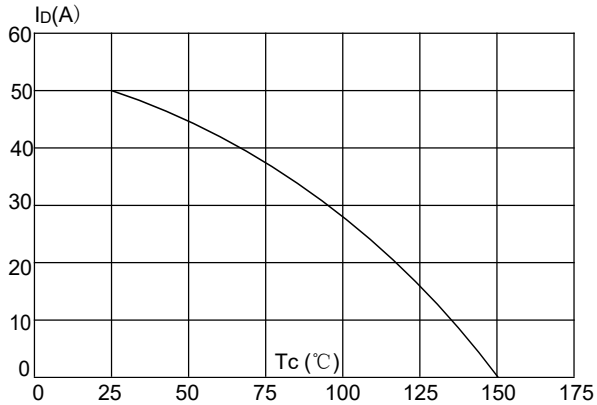
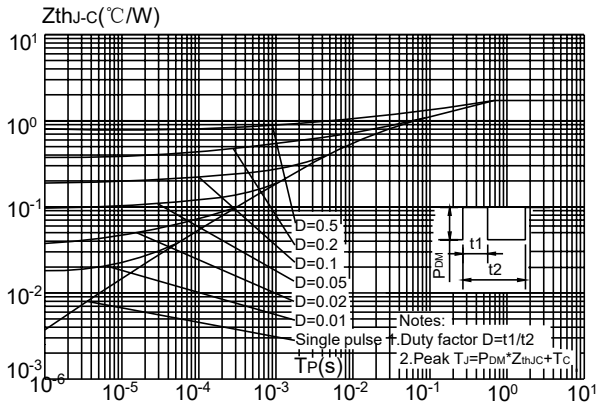


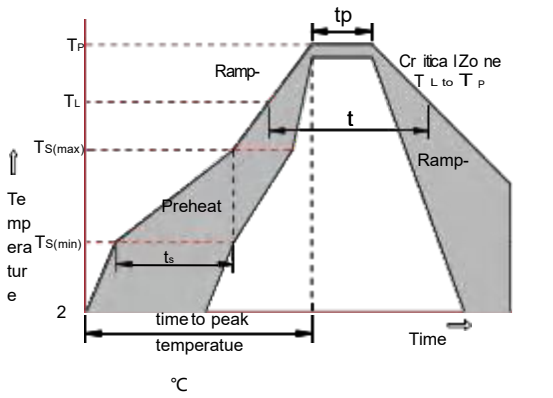

**Figure.11:** Maximum Effective Transient Thermal Impedance, Junction-to-Case



## Soldering parameters

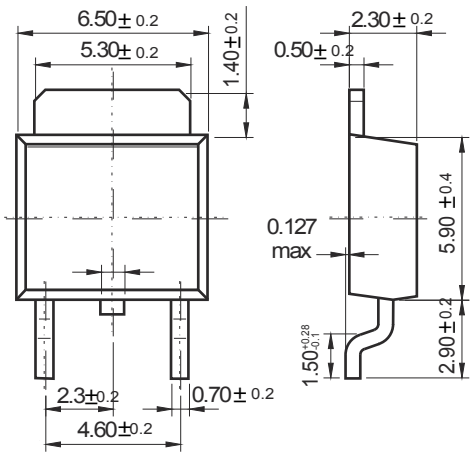
| Reflow Condition | | Pb-Free assembly (see as bellow) |
|---|---|---|
| Pre Heat | -Temperature Min ($T_{s(min)}$) | +150℃ |
| | -Temperature Max($T_{s(max)}$) | +200℃ |
| | -Time (Min to Max) (ts) | 60-180 secs. |
| Average ramp up rate (Liquid us Temp ($T_L$) to peak) | | 3℃/sec. Max |
| $T_{s(max)}$ to $T_L$ - Ramp-up Rate | | 3℃/sec. Max |
| Reflow | -Temperature($T_L$)(Liquid us) | +217℃ |
| | -Temperature($t_L$) | 60-150 secs. |
| Peak Temp ($T_p$) | | +260(+0/-5)℃ |
| Time within 5℃ of actual Peak Temp ($t_p$) | | 30 secs. Max |
| Ramp-down Rate | | 6℃/sec. Max |
| Time 25℃ to Peak Temp ($T_P$) | | 8 min. Max |
| Do not exceed | | +260℃ |

**FIG5:** Reflow condition

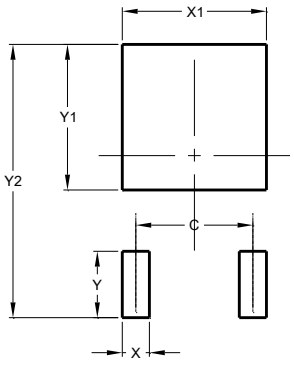



## Package Dimensions & Suggested Pad Layout

TO-252



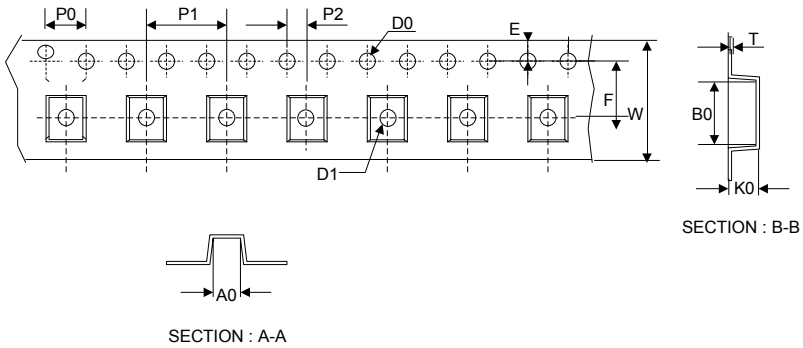

Dimensions in inches and (millimeters)



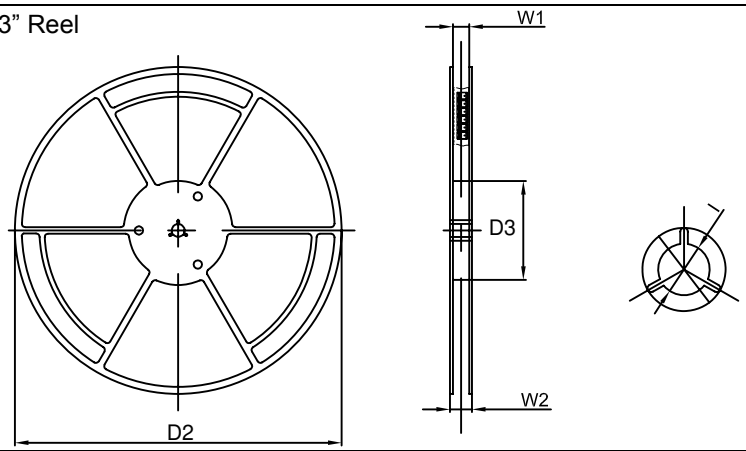

| Dimensions | Value (in mm) |
|---|---|
| C | 4.55 |
| X | 1.50 |
| X1 | 5.80 |
| Y | 2.70 |
| Y1 | 6.00 |
| Y2 | 10.90 |

## Tape & rell specification

Tape




13” Reel




| Symbol | Dimension (mm) |
|---|---|
| P0 | 4.00±0.20 |
| P1 | 8.00±0.20 |
| P2 | 2.00±0.20 |
| D0 | 1.55±0.15 |
| D1 | 1.55±0.20 |
| E | 1.75±0.20 |
| F | 7.50±0.20 |
| W | 16.00±0.20 |
| A0 | 7.10±0.20 |
| B0 | 10.50±0.20 |
| K0 | 2.70±0.20 |
| T | 0.30±0.10 |
| D2 | 330.0±5.0 |
| D3 | 100.0±4.0 |
| W1 | 20.0±5.0 |
| W2 | 25.0±5.0 |
| I | 13.0±2.0 |

Quantity: 2500PCS

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